## NSN 5962-01-163-3013

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propagation delay time, high to low level

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	ngth:
1.290 inc	hes
Body Wi	dth:
Between	0.500 inches and 0.610 inches
Body He	ight:
Between	0.150 inches and 0.210 inches
Maximur	n Power Dissipation Rating:
1.02 watt	S
Operatin	g Tempurature Range:
-55.0/+12	25.0 degrees celsius
Storage	Tempurature Range:
-65.0/+15	50.0 degrees celsius
End App	lication:
Radar sy	stem an/fps-117
Features	Provided:
Hermetic	ally sealed and monolithic and programmable and bipolar and schottky and high impedance
Inclosur	e Material:
Ceramic	and glass
Inclosur	e Configuration:
Dual-in-li	ne
Output L	.ogic Form:
Transisto	r-transistor logic
Input Cir	cuit Pattern:
13 input	
Case Ou	tline Source And Designator:
D-3 mil-n	า-38510
Termina	Surface Treatment:
Solder	
Voltage	Rating And Type Per Characteristic:
5.5 volts	power source
Time Ra	ting Per Chacteristic:
90.00 na	noseconds propagation delay time, low to high level output and 90.00 nanoseconds propag
output	
Memory	Device Type:
Rom	
Memory	Capacity:
Unknown	I
Termina	Type And Quantity:
24 printe	d circuit
Shelf Life	e:
N/a	

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## Demilitarization:

Yes - demil/mli

Fiig:

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